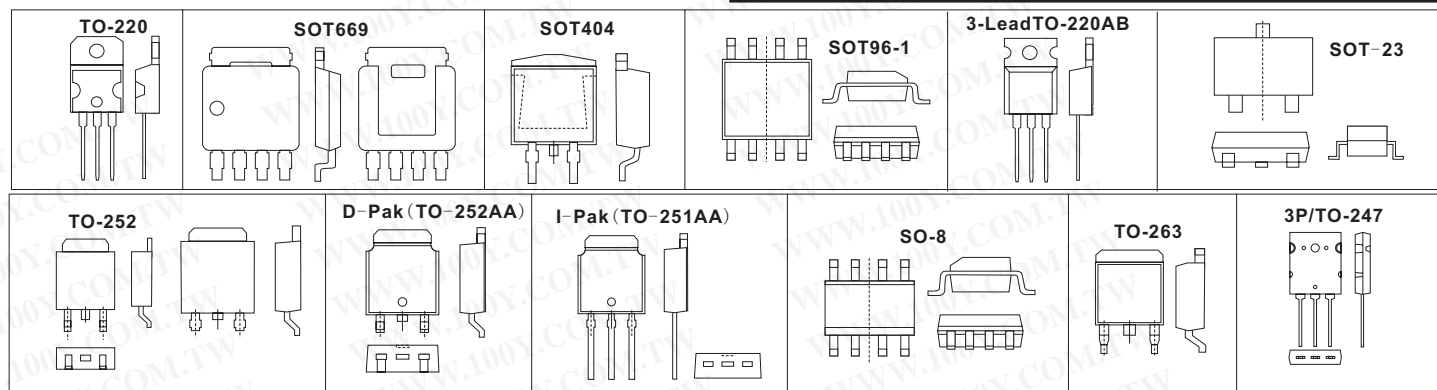


二极管+电晶体+模块

其它系列功率场效电晶体

详细产品规格 - 请点击 cn.100y.com.tw



100Y 编号	厂商编号	制造厂商	说明	Pin/Package	Id(max.) A	Rds(on)(max.) Ω	Pd(max.) W	Vdss(max.) V	N/P Ch.
43104	P40NF10L	ST(SGS)	40A, 100V, 0.040 Ohm, N-Channel Power MOSFETs	TO-220AB	40A	0.04Ω	160W	100V	N-Ch.
39540	PC827	Infineon	OptiMOS Power-Transistor	TO-220	80A	7mΩ			N
29485	PH16030L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	38A	16.9mΩ	41.6W	30V	N-ch.
29487	PH2520U	PHILIPS	PHILIPS_功率场效电晶体	SOT669	121A	2.5mΩ	62.5W	20V	N-ch.
29488	PH2625L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	100A		62.5W	25V	N-ch.
29489	PH2925U	PHILIPS	PHILIPS_功率场效电晶体	SOT669	100A	2.9mΩ	62.5W	25V	N-ch.
29490	PH3120L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	100A	2.65mΩ	62.5W	20V	N-ch.
29491	PH3230S	PHILIPS	PHILIPS_功率场效电晶体	SOT669	100A	6.5mΩ	62.5W	30V	N-ch.
29492	PH3830L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	98A	3.8mΩ	62.5W	30V	N-ch.
29493	PH4530L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	80A	5.7mΩ	62.5W	30V	N-ch.
29494	PH4840S	PHILIPS	PHILIPS_功率场效电晶体	SOT669	94.5 A	4.1 mΩ	62.5W	40 V	N-ch.
29496	PH5330E	PHILIPS	PHILIPS_功率场效电晶体	SOT669	80A	5.7mΩ	62.5W	30V	N-Ch.
29497	PH6325L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	78.7 A		62.5W	25V	N-ch.
29507	PH7030L	PHILIPS	PHILIPS_功率场效电晶体	SOT669	68A	7.9mΩ	62.5W	30V	N-Ch.
29508	PH8230E	PHILIPS	PHILIPS_功率场效电晶体	SOT669	67A	8.2mΩ	62.5W	30V	N-Ch.
29509	PHB101NQ04T	PHILIPS	PHILIPS_功率场效电晶体	SOT404	75A	8mΩ	157W	40V	N-Ch.
37693	PHB4ND40E	PHILIPS	PowerMOS transistor FREDFET, Avalanche energy rated	SOT-404	4.4 A	1.8 Ω	83W	400 V	N
29467	PHK04P02T	PHILIPS	PHILIPS_功率场效电晶体	SOT96-1	-4.66 A	0.15Ω		-16 V	P-Ch.
29510	PHP101NQ04T	PHILIPS	PHILIPS_功率场效电晶体	TO-220AB	75A	8mΩ	157W	40V	N-Ch.
37692	PHP4ND40E	PHILIPS	PowerMOS transistor FREDFET, Avalanche energy rated	TO-220AB	4.4 A	1.8 Ω	83W	400 V	N
29469	PMV65XP	PHILIPS	PHILIPS_功率场效电晶体	SOT23	-3.9A	76mΩ	1.92W	-20V	P-ch.
42028	RD15HV F1	MITSUBISHI	a MOS FET type transistor specificallydesigned for VHF/UHF High power amplifiers applications	TO-220	4A		48W	20v	
13885	RFD10P03LSM	Fairchild	P-Ch. Power MOSFET	2P/TO-252	10A	0.2Ω	60W	30V	P
28876	RFD14N05	Intersil	功率场效应电晶体	3P/TO-251AA	14A	0.1Ω		50V	N-Ch
17589	RFD14N05	Fairchild	Logic Level Power MOSFET	TO-252AA	14A	0.1Ohm		50V	N-Ch.
14579	RFD14N05L	Intersil	Power MOSFET	3P/TO-251AA	14A	0.1Ω		50V	N-Ch
45101	RFD14N05L	Fairchild	14A, 50V, 0.100 Ohm, Logic Level, N-Channel Power MOSFETs	3P/TO-251AA	14A	0.1Ω	48W	50V	N-Ch.
3933	RFD15P05	Intersil	P-Ch. Power MOSFET	TO-251(I-Pak)	15A	0.15Ω	67.5W	50V	P
12987	RFD15P05SM	HARRIS	P-Channel Power MOSFET	2P/TO-252(16)	15A	0.15Ω	80W	50V	P
3931	RFD16N05	Fairchild	Logic Level,N-Ch. Power MOSFETs	3P/TO-251(I-Pak)	16A	0.047Ω	60W	50V	N
39548	RFD3055LES M	Fairchild	Surface Mount and Through-Hole Power MOSFETs	TO-252AA	11A	0.107	38W	60V	
34612	RFP30P05	Intersil	30A, 50V, 0.065 Ohm, P-Channel Power MOSFETs	TO-220AB	30A		120W	-50V	P-Channel
3938	RFP50N06	HARRIS	N-Ch. Power MOSFET	3P/TO-220	50A	0.022Ω	131W	60V	N
42836	RFP70N06	Fairchild	N-Channel Power70A, 60V, 0.014 Ohm, N-Channel Power MOSFETsr MOSFET	3P/TO-220AB	70A	0.014Ω	150W	60V	N
3939	RFP70N06	HARRIS	N-Channel Power MOSFET	3P/TO-220	70A	0.014Ω	150W	60V	N
31991	SI4420DY		N-Ch. Enhancement Mode Field Effect Transistor	8P/SO-8					N-Ch.
22019	SI4431DY	Fairchild	P-Ch. Logic Level Enhancement Mode Field Effect Transistor	8P/SO-8	±5.8A	0.029Ω	2.5W	-30V	P-Ch.
29495	SI4814DY-T1-E3	VISHAY	VISHAY_功率场效电晶体	SO-8					N-Ch.
40067	SI4835DY	VISHAY	P-Channel 30-V (D-S) MOSFET	SO-8				-30V	P-Channel
35264	SI4936DY	Fairchild	Dual N-Channel Enhancement Mode MOSFET	SO-8	30A		2W	30V	N-Channel
35271	SI4980DY	Fairchild	Dual N-Channel 80-V (D-S) MOSFET	SO-8	30A		2w	80v	N-Channel
35278	SI9410DY	Fairchild	Single N-Channel Enhancement Mode MOSFET	SO-8	30A		2.5W	30V	N-Channel
34132	SPB07N60S5	Infineon	Cool MOS? Power Transistor	TO-263	7.3A	0.6Ω		600V	
29126	SPD03N60S5	Infineon	功率场效电晶体	TO-252	3.2A	1.4?		600V	N Ch.
29127	SPP02N60S5	Infineon	功率场效电晶体	TO-220	1.8A	3?		600V	N Ch.
34131	SPP02N60S5	Infineon	Cool MOS? Power Transistor	TO-220	1.8A	3Ω		600V	
29083	SPP04N60S5	Infineon	功率场效电晶体	TO-220	4.5A	0.95	40W	200V	N Ch.
34123	SPP04N60S5	Infineon	Cool MOS? Power Transistor	TO-220	4.5A	0.95Ω		600V	
29130	SPP07N60S5	Infineon	功率场效电晶体	TO-220	7.3A	0.6?		600V	N Ch.
34127	SPP11N60S5	Infineon	Cool MOS? Power Transistor	TO-220	11A	0.38Ω		600V	
29072	SPP20N60C2	Infineon	功率场效电晶体	TO-220-3L	20A	0.19Ω		600V	N Ch.



服务专线: 台湾: 886-3-5753170
 传 真: 台湾: 886-3-5753172
 E-mail: 台湾: sale@100y.com.tw

深圳: 86-755-83298787
 深圳: 86-755-83640655
 深圳: 100y@163.com

上海: 86-21-34970699
 上海: 86-21-64605107
 上海: 100y-1@163.com